

C0805H123J3GACTU

Specifications

Insulation Resistance

Aliases (C0805H123J3GAC7800) SMD Indust COG HT200C, Ceramic, 0.012 uF, 5%, 25 VDC, COG, SMD, MLCC, High Temperature, Ultra-Stable, Low Loss, 0805, 0.7 mm



General Information	
Series	SMD Indust COG HT200C
Style	SMD Chip
Description	SMD, MLCC, High Temperature, Ultra-Stable, Low Loss
Features	High Temp, Ultra-Stable, Low Loss
RoHS	Yes
Termination	Tin
Marking	No
AEC-Q200	No
Typical Component Weight	11 mg
Shelf Life	78 Weeks
MSL	1

Dimensions	
Chip Size	0805
L	2mm +/-0.2mm
W	1.25mm +/-0.2mm
Т	0.78mm +/-0.10mm
S	0.7mm MIN
В	0.5mm +/-0.25mm

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Capacitance	0.012 uF
Measurement Condition	1 kHz 1.0Vrms
Tolerance	5%
Voltage DC	25 VDC
Dielectric Withstanding Voltage	62.5 VDC
Temperature Range	-55/+200°C
Temp. Coefficient	COG
Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC)	30 ppm/C, 1kHz 1.0Vrms
Dissipation Factor	0.1% 1 kHz 1.0Vrms
Aging Rate	0% Loss/Decade Hour

83.3333 GOhms

Packaging Specifications	
Packaging	T&R, 180mm, Paper Tape
Packaging Quantity	4000

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